**Thyristor Module** 

## MCMA650MT1400NKD

$V_{RRM}$	=	1400 V
I <sub>tav</sub>	=	300 A
V <sub>T</sub>	=	1.02 V

1~ Triac

### Part number

### MCMA650MT1400NKD



Backside: isolated **E**72873



### Features / Advantages:

- Triac for line frequency
- Three Quadrants Operation - QI - QIII
- Planar passivated chip
- Long-term stability
  - of blocking currents and voltages



### **Applications:**

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: Y1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting

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- Base plate: Copper
- internally DCB isolated
- Advanced power cycling

### Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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## MCMA650MT1400NKD

Rectifier				1	Rating	<b>)</b>	1
Symbol	Definition	Conditions		min.	typ.	max.	Un
V <sub>RSM/DSM</sub>	max. non-repetitive reverse/forward	blocking voltage	$T_{VJ} = 25^{\circ}C$			1500	`
V <sub>RRM/DRM</sub>	max. repetitive reverse/forward block	8 8	$T_{VJ} = 25^{\circ}C$			1400	١
R/D	reverse current, drain current	$V_{R/D} = 1400 V$	$T_{vJ} = 25^{\circ}C$			1	m/
		$V_{R/D} = 1400 V$	$T_{vJ} = 125^{\circ}C$			40	m/
V <sub>T</sub>	forward voltage drop	I <sub>T</sub> = 300 A	$T_{VJ} = 25^{\circ}C$			1.09	١
		$I_{T} = 600 \text{ A}$				1.26	١
		$I_{T} = 300 \text{ A}$	T <sub>vJ</sub> = 125°C			1.02	١
		$I_{T} = 600 \text{ A}$				1.23	١
ITAV	average forward current	T <sub>c</sub> = 85°C	T <sub>v.i</sub> = 140°C			300	/
IRMS	RMS forward current per phase	180° sine				650	ļ
V <sub>T0</sub>	threshold voltage		T <sub>v1</sub> = 140°C			0.81	١
r <sub>T</sub>	slope resistance { for power loss	calculation only	vj			0.68	m۵
R <sub>thJC</sub>	thermal resistance junction to case					0.12	K/W
R <sub>thCH</sub>	thermal resistance case to heatsink				0.040	0.12	K/W
P <sub>tot</sub>			$T_c = 25^{\circ}C$		0.040	960	Ŵ
-	total power dissipation max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{c} = 25 \text{ C}$ $T_{v,i} = 45^{\circ}\text{C}$			9.60	k/
I <sub>TSM</sub>	max. Iorward Surge Current						
		t = 8,3 ms; (60 Hz), sine	$V_{\rm R} = 0 V$			10.4	k/
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 140 ^{\circ}\text{C}$			8.16	k/
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			8.82	k/
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			460.8	1
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			447.4	kA <sup>2</sup>
		t = 10 ms; (50 Hz), sine	$T_{vJ} = 140^{\circ}C$			332.9	kA <sup>2</sup>
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			323.3	kA <sup>2</sup>
C	junction capacitance	$V_{R}$ = 400 V f = 1 MHz	$T_{vJ} = 25^{\circ}C$		438		pl
₽ <sub>GM</sub>	max. gate power dissipation	t <sub>P</sub> = 30 μs	$T_c = 140^{\circ}C$			120	V
		t <sub>P</sub> = 300 μs				60	V
P <sub>GAV</sub>	average gate power dissipation					20	v
(di/dt) <sub>cr</sub>	critical rate of rise of current	T <sub>v,l</sub> = 140 °C; f = 50 Hz re	epetitive, $I_{T} = 900 \text{ A}$			100	A/μ
		$t_{P} = 200 \mu s; di_{G}/dt = 1 A/\mu s; -$	-				
			on-repet., $I_{\tau} = 300 \text{ A}$			500	A/µ
(dv/dt) <sub>cr</sub>	critical rate of rise of voltage	$V = \frac{2}{3} V_{\text{DRM}}$	T <sub>vi</sub> = 140°C			1000	i
(ac) acycr		$R_{GK} = \infty$ ; method 1 (linear volta					
V <sub>gT</sub>	gate trigger voltage	$V_{\rm D} = 6 \text{ V}$	$\frac{1}{T_{vJ}} = 25^{\circ}C$			2	١
▼ GT	gale ingger renage	vB = C v	$T_{vJ} = -40^{\circ}C$			3	N
	acto triagor ourrept					_	
I <sub>GT</sub>	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			220	m/
.,		NI 2/ NI	$T_{VJ} = -40^{\circ}C$			400	m/
V <sub>GD</sub>	gate non-trigger voltage	$V_{D} = \frac{2}{3} V_{DRM}$	$T_{vJ} = 140^{\circ}C$			0.25	\ \
I <sub>GD</sub>	gate non-trigger current					10	
I.	latching current	$t_p = 30 \ \mu s$ $I_G = 1 \ A; \ di_G / dt = 1 \ A / \mu s$	$T_{VJ} = 25^{\circ}C$			200	m/
I <sub>H</sub>	holding current	$V_{\rm D} = 6 \ V \ R_{\rm GK} = \infty$	$T_{vJ} = 25 ^{\circ}C$			150	m/
t <sub>gd</sub>	gate controlled delay time	$V_{\rm D} = \frac{1}{2} V_{\rm DRM}$	T <sub>vJ</sub> = 25°C			2	i
gu		$I_{\rm G} = 1 {\rm A};  {\rm di}_{\rm G}/{\rm dt} = 1 {\rm A}/\mu{\rm s}$				-	P**
+	turn-off time	$V_{\rm B} = 100 \text{ V}; \text{ I}_{\rm T} = 300 \text{ A}; \text{ V} = 320 \text{ A}; \text{ V} = 320 \text{ A}; \text{ V} = 3200 \text{ A}; \text{ A} = 3200 \text{ A}; $			350		
t <sub>q</sub>		$v_{\rm R} = 100 v, i_{\rm T} = 300 A, v = 7$	3 VDRM IVJ = 120 U		550		μ

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## MCMA650MT1400NKD

Package Y1			1	Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
	RMS current	per terminal				600	Α
T <sub>vj</sub>	virtual junction temperature			-40		140	°C
T <sub>op</sub>	operation temperature			-40		125	°C
T <sub>stg</sub>	storage temperature			-40		125	°C
Weight					650		g
M <sub>D</sub>	mounting torque			4.5		7	Nm
M <sub>T</sub>	terminal torque			11		13	Nm
d <sub>Spp/App</sub>	creepage distance on surface   striking distance through air		terminal to terminal	16.0			mm
d <sub>Spb/Apb</sub>	creepage distance on surrac	e   striking distance through an	terminal to backside	25.0			mm
V	isolation voltage	t = 1 second		3600			V
	t =	t = 1 minute	50/60 Hz, RMS; liso∟ ≤ 1 mA	3000			V



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

### Part description

- M = Module

- M = Module C = Thyristor (SCR) M = Thyristor A = (up to 1800V) 650 = Current Rating [A]
- MT = 1~ Triac
- 1400 = Reverse Voltage [V] N = Three Quadrants operation: QI - QIII KD = Y1-2-CU

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA650MT1400NKD	MCMA650MT1400NKD	Box	3	518703

Similar Part	Package	Voltage class
MCMA650MT1800NKD	Y1-2-CU	1800

Equiva	alent Circuits for	Simulation	* on die level	$T_{VJ} = 140 \ ^{\circ}C$
	)[R	Thyristor		
V <sub>0 max</sub>	threshold voltage	0.81		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	0.5		mΩ

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## MCMA650MT1400NKD

### Outlines Y1



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red Type ZY 180L (L = Left for pin pair 4/5) Type ZY 180R (R = Right for pin pair 6/7) UL 758, style 3751



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## MCMA650MT1400NKD

### Thyristor



8000

7000

6000

5000

4000

 $T_{VJ} = 140$  °C

0.01

I<sub>TSM</sub>

[A]

Fig. 1 Forward characteristics



Fig. 4 Gate voltage & gate current



50 Hz, 80% V

= 45°C

0.1

t [s]

 $I_{TSM}$ : crest value, t: duration

Fig. 2 Surge overload current

Fig. 5 Gate controlled delay time  $t_{ad}$ 

0.06

0.05

0.04

0.03

0.02

0.01

i

1

2

3

4

 $\mathbf{R}_{thi}$  (K/W)

0.0020

0.0080

0.0130

0.0370

0.0150

0.0800

0.2200

0.3800

t<sub>i</sub> (s)



Fig. 3 I<sup>2</sup>t versus time (1-10 s)



1000



Fig. 7b and ambient temperature



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10000